NSN 5961-01-114-8339

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Inclosure Material:

Metal

Overall Length:

1.540 inches

Overall Height:

0.374 inches

Overall Width:

0.992 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact-darlington connected

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage/static/emitter open and 100.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

20.00 amperes source cutoff current

Power Rating Per Characteristic:

225.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

1 case and 2 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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